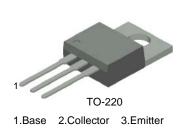


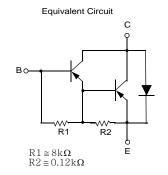
August 2008

TIP145T/146T/147T PNP Epitaxial Silicon Darlington Transistor

Monolithic Construction With Built In Base-Emitter Shunt Resistors

- High DC Current Gain : $h_{FE} = 1000 @ V_{CE} = -4V$, $I_C = -5A$ (Min.)
- Industrial Use
- Complement to TIP140T/141T/142T





Absolute Maximum Ratings * T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
BV _{CBO}	Collector-Base Voltage : TIP145T : TIP146T : TIP147T	- 60 - 80 - 100	V V V
BV _{CEO}	Collector-Emitter Voltage : TIP145T : TIP146T : TIP147T	- 60 - 80 - 100	V V V
BV _{EBO}	Emitter-Base Voltage	- 5	V
Ic	Collector Current (DC)	- 10	Α
I _{CP}	Collector Current (Pulse)	- 15	Α
I _B	Base Current (DC)	- 0.5	А
P _C	Collector Dissipation (T _C =25°C)	80	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Junction Temperature Range	- 65 ~ 150	°C

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^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics * T_C=25°C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Тур.	Max	Units
V _{CEO} (sus)	Collector-Emitter Sustaining Voltage : TIP145T : TIP146T : TIP147T	I _C = - 30mA, I _B = 0	- 60 - 80 - 100			V V V
I _{CEO}	Collector Cut-off Current : TIP145T : TIP146T : TIP147T	$V_{CE} = -30V, I_{B} = 0$ $V_{CE} = -40V, I_{B} = 0$ $V_{CE} = -50V, I_{B} = 0$			- 2 - 2 - 2	mA mA mA
I _{CBO}	Collector Cut-off Current : TIP145T : TIP146T : TIP147T	$V_{CB} = -60V, I_{E} = 0$ $V_{CB} = -80V, I_{E} = 0$ $V_{CB} = -100V, I_{E} = 0$			- 1 - 1 - 1	mA mA mA
I _{EBO}	Emitter Cut-off Current	V _{BE} = - 5V, I _C = 0			- 2	mA
h _{FE}	DC Current Gain	V _{CE} = - 4V, I _C = - 5A V _{CE} = - 4V, I _C = - 10A	1000 500			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = - 5A, I _B = - 10mA I _C = - 10A, I _B = - 40mA			- 2 - 3	V V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = - 10A, I _B = - 40mA			- 3.5	V
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} = - 4V, I _C = - 10A			- 3	V
t _d	Delay Time	V _{CC} = - 30V, I _C = - 5A		0.15		μs
t _r	Rise Time	$I_{B1} = -20 \text{mA}, I_{B2} = 20 \text{mA}$ $R_1 = 6\Omega$		0.55		μS
t _{stg}	Storage Time	1		2.5		μS
t _f	Fall Time			2.5		μs

^{*} Pulse Test: Pulse Width≤300μs, Duty Cycle≤2%

Typical Characteristics

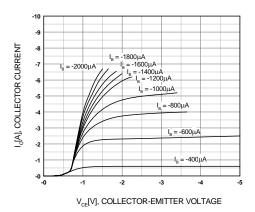


Figure 1. Static Characteristic

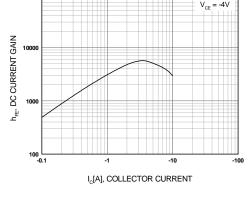


Figure 2. DC current Gain

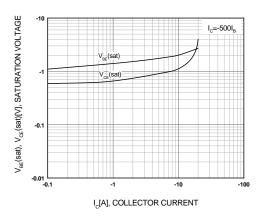


Figure 3. Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage

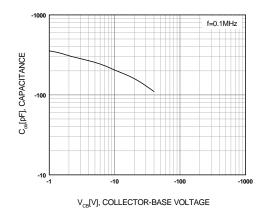


Figure 4. Collector Output Capacitance

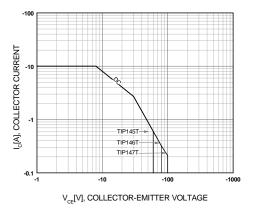


Figure 5. Safe Operating Area

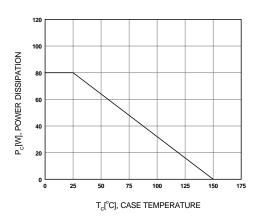
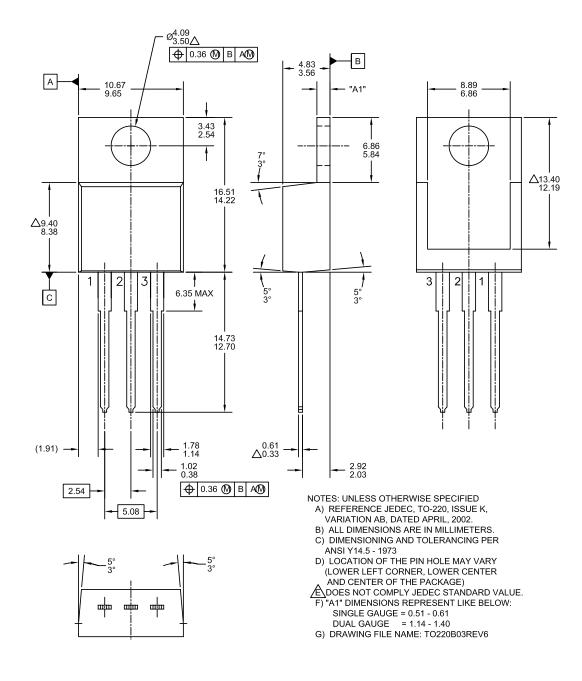


Figure 6. Power Derating

Mechanical Dimensions

TO220







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